Octal 3-State Noninverting Buffer/Line Driver/Line Receiver

High-Performance Silicon-Gate CMOS

The MC54/74HC241A is identical in pinout to the LS241. The device inputs are compatible with standard CMOS outputs; with pullup resistors, they are compatible with LSTTL outputs.

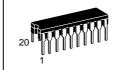
This octal noninverting buffer/line driver/line receiver is designed to be used with 3-state memory address drivers, clock drivers, and other sub-oriented systems. The device has noninverted outputs and two output enables. Enable A is active-low and Enable B is active-high.

The HC241A is similar in function to the HC244A and HC240A.

- Output Drive Capability: 15 LSTTL Loads
- · Outputs Directly Interface to CMOS, NMOS, and TTL
- · Operating Voltage Range: 2 to 6 V
- Low Input Current: 1 μA
- · High Noise Immunity Characteristic of CMOS Devices
- In Compliance with the Requirements Defined by JEDEC Standard No. 7A
- Chip Complexity: 134 FETs or 33.5 Equivalent Gates

LOGIC DIAGRAM 18 YA2 A3 <u>6</u> YA3 12 YA4 DATA **NONINVERTING INPUTS OUTPUTS** B1 _11 YB1 B3 <u>15</u> 5 YB3 B4 <u>17</u> 3 PIN 20 = V_{CC} PIN 10 = GND OUTPUT | ENABLE A 1 ENABLE B 19 ENABLES

MC54/74HC241A



J SUFFIX
CERAMIC PACKAGE
CASE 732-03



N SUFFIX PLASTIC PACKAGE CASE 738–03

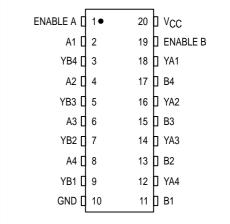


DW SUFFIX SOIC PACKAGE CASE 751D-04

ORDERING INFORMATION

MC54HCXXXAJ Ceramic MC74HCXXXAN Plastic MC74HCXXXADW SOIC

PIN ASSIGNMENT



FUNCTION TABLE

Input	s	Output	Inputs		Output
Enable			Enable		
Α	Α	YA	в в		YB
L	L	L	Н	L	L
L	Н	Н	H	Н	Н
Н	Χ	Z	L	Х	Z

Z = high impedance

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REV 7

MC54/74HC241A

MAXIMUM RATINGS*

Symbol	Parameter	Value	Unit
VCC	DC Supply Voltage (Referenced to GND)	- 0.5 to + 7.0	V
V _{in}	DC Input Voltage (Referenced to GND)	-0.5 to V _{CC} + 0.5	V
V _{out}	DC Output Voltage (Referenced to GND)	-0.5 to V _{CC} + 0.5	V
l _{in}	DC Input Current, per Pin	± 20	mA
l _{out}	DC Output Current, per Pin	± 35	mA
ICC	DC Supply Current, V _{CC} and GND Pins	± 75	mA
PD	Power Dissipation in Still Air, Plastic or Ceramic DIP† SOIC Package†	750 500	mW
T _{stg}	Storage Temperature	- 65 to + 150	°C
TL	Lead Temperature, 1 mm from Case for 10 Seconds (Plastic DIP or SOIC Package) (Ceramic DIP)	260 300	°C

This device contains protection circuitry to guard against damage due to high static voltages or electric fields. However, precautions must be taken to avoid applications of any voltage higher than maximum rated voltages to this high–impedance circuit. For proper operation, V_{in} and V_{out} should be constrained to the range GND \leq (V_{in} or V_{out}) \leq V_{CC} .

Unused inputs must always be tied to an appropriate logic voltage level (e.g., either GND or V_{CC}). Unused outputs must be left open.

SOIC Package: - 7 mW/°C from 65° to 125°C

For high frequency or heavy load considerations, see Chapter 2 of the Motorola High-Speed CMOS Data Book (DL129/D).

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Min	Max	Unit
VCC	DC Supply Voltage (Referenced to GND)	2.0	6.0	V
V _{in} , V _{out}	DC Input Voltage, Output Voltage (Referenced to GND)	0	Vcc	V
T _A	Operating Temperature, All Package Types	- 55	+ 125	°C
t _r , t _f	Input Rise and Fall Time $V_{CC} = 2.0 \text{ V}$ (Figure 1) $V_{CC} = 4.5 \text{ V}$ $V_{CC} = 6.0 \text{ V}$	0 0 0	1000 500 400	ns

DC ELECTRICAL CHARACTERISTICS (Voltages Referenced to GND)

					Guaranteed Limit		mit	
Symbol	Parameter	Test Co	onditions	V _C C V	– 55 to 25°C	≤ 85°C	≤ 125°C	Unit
VIH	Minimum High–Level Input Voltage	$V_{\text{out}} = V_{\text{CC}} - 0.$ $ I_{\text{out}} \le 20 \mu\text{A}$	1 V	2.0 3.0 4.5 6.0	1.5 2.1 3.15 4.2	1.5 2.1 3.15 4.2	1.5 2.1 3.15 4.2	V
V _{IL}	Maximum Low-Level Input Voltage	$V_{out} = 0.1 \text{ V}$ $ I_{out} \le 20 \mu\text{A}$		2.0 3.0 4.5 6.0	0.5 0.9 1.35 1.8	0.5 0.9 1.35 1.8	0.5 0.9 1.35 1.8	V
VOH	Minimum High–Level Output Voltage	$V_{\text{in}} = V_{\text{IH}}$ $ I_{\text{Out}} \le 20 \mu\text{A}$		2.0 4.5 6.0	1.9 4.4 5.9	1.9 4.4 5.9	1.9 4.4 5.9	V
		V _{in} = V _{IH}	$\begin{aligned} I_{Out} &\leq 2.4 \text{ mA} \\ I_{Out} &\leq 6.0 \text{ mA} \\ I_{Out} &\leq 7.8 \text{ mA} \end{aligned}$	3.0 4.5 6.0	2.48 3.98 5.48	2.34 3.84 5.34	2.2 3.7 5.2	
VOL	Maximum Low–Level Output Voltage	$V_{in} = V_{IL}$ $ I_{out} \le 20 \mu\text{A}$		2.0 4.5 6.0	0.1 0.1 0.1	0.1 0.1 0.1	0.1 0.1 0.1	V
		V _{in} = V _{IL}	$ I_{Out} \le 2.4 \text{ mA}$ $ I_{Out} \le 6.0 \text{ mA}$ $ I_{Out} \le 7.8 \text{ mA}$	3.0 4.5 6.0	0.26 0.26 0.26	0.33 0.33 0.33	0.4 0.4 0.4	

^{*} Maximum Ratings are those values beyond which damage to the device may occur. Functional operation should be restricted to the Recommended Operating Conditions.

[†]Derating — Plastic DIP: – 10 mW/°C from 65° to 125°C Ceramic DIP: – 10 mW/°C from 100° to 125°C

DC ELECTRICAL CHARACTERISTICS (Voltages Referenced to GND)

				Gu	aranteed Li	mit	
Symbol	Parameter	Test Conditions	V _{CC}	– 55 to 25°C	≤ 85°C	≤ 125°C	Unit
l _{in}	Maximum Input Leakage Current	V _{in} = V _{CC} or GND	6.0	± 0.1	± 1.0	± 1.0	μΑ
loz	Maximum Three–State Leakage Current	Output in High-Impedance State V _{in} = V _{IL} or V _{IH} V _{out} = V _{CC} or GND	6.0	± 0.5	± 5.0	± 10	μΑ
ICC	Maximum Quiescent Supply Current (per Package)	V _{in} = V _{CC} or GND I _{out} = 0 µA	6.0	4.0	40	160	μА

NOTE: Information on typical parametric values along with high frequency or heavy load considerations, can be found in Chapter 2 of the Motorola High–Speed CMOS Data Book (DL129/D).

AC ELECTRICAL CHARACTERISTICS ($C_L = 50 \text{ pF}$, Input $t_f = t_f = 6.0 \text{ ns}$)

			Guaranteed Limit			
Symbol	Parameter	V _{CC}	– 55 to 25°C	≤ 85°C	≤ 125°C	Unit
tPLH, tPHL	Maximum Propagation Delay, Input A to Output Y (Figures 1 and 3)	2.0 3.0 4.5 6.0	90 45 18 15	115 60 23 20	135 70 27 23	ns
tPLZ, tPHZ	Maximum Propagation Delay, Output Enable to Y (Figures 2 and 4)	2.0 3.0 4.5 6.0	120 60 24 20	150 70 30 26	180 80 36 31	ns
^t PZL [,] ^t PZH	Maximum Propagation Delay, Output Enable to Y (Figures 2 and 4)	2.0 3.0 4.5 6.0	90 60 18 15	115 70 23 20	135 80 27 23	ns
t _{TLH} , t _{THL}	Maximum Output Transition Time, Any Output (Figures 1 and 3)	2.0 3.0 4.5 6.0	60 23 12 10	75 27 15 13	90 32 18 15	ns
C _{in}	Maximum Input Capacitance	_	10	10	10	pF
C _{out}	Maximum Three–State Output Capacitance (Output in High–Impedance State)	_	15	15	15	pF

NOTE: For propagation delays with loads other than 50 pF, and information on typical parametric values, see Chapter 2 of the Motorola High–Speed CMOS Data Book (DL129/D).

		Typical @ 25° C, $V_{CC} = 5.0 \text{ V}$	
C _{PD}	Power Dissipation Capacitance (Per Transceiver Channel)*	34	pF

^{*} Used to determine the no–load dynamic power consumption: P_D = C_{PD} V_{CC}²f + I_{CC} V_{CC}. For load considerations, see Chapter 2 of the Motorola High–Speed CMOS Data Book (DL129/D).

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SWITCHING WAVEFORMS

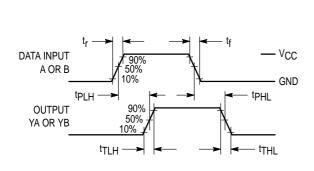
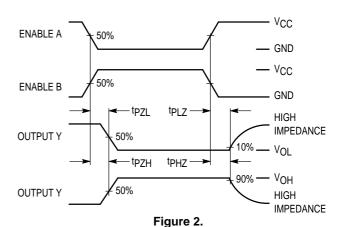


Figure 1.





^{*} Includes all probe and jig capacitance

Figure 3. Test Circuit

* Includes all probe and jig capacitance

Figure 4. Test Circuit

PIN DESCRIPTIONS

INPUTS

A1, A2, A3, A4, B1, B2, B3, B4 (Pins 2, 4, 6, 8, 11, 13, 15, 17)

Data input pins. Data on these pins appear in noninverted form on the corresponding Y outputs when the outputs are enabled.

CONTROLS

Enable A (Pin 1)

Output enable (active—low). When a low level is applied to this pin, the outputs of the "A" devices are enabled and the devices function as noninverting buffers. When a high level is applied, the outputs assume the high—impedance state.

Enable 8 (Pin 19)

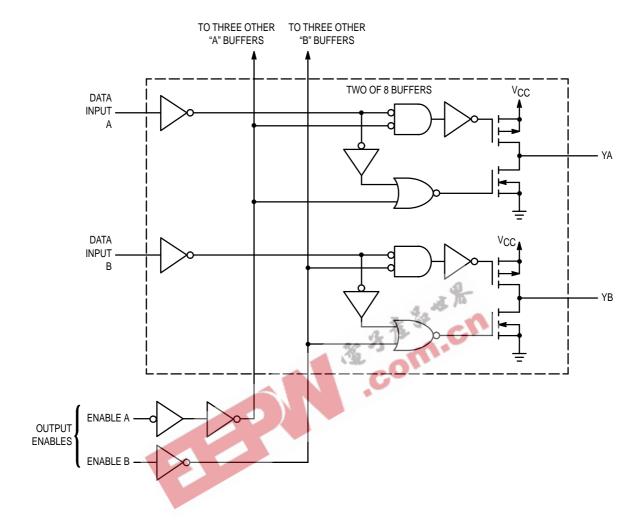
Output enable (active—high). When a high level is applied to this pin, the outputs of the "B" devices are enabled and the devices function as noninverting buffers. When a low level is applied, the outputs assume the high—impedance state.

OUTPUTS

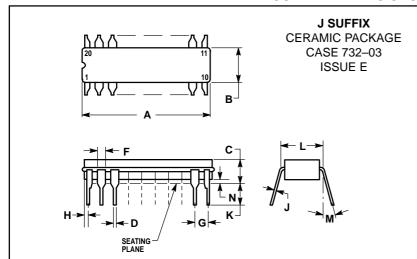
YA1, YA2, YA3, YA4, YB1, YB2, YB3, YB4 (Pins 18, 16, 14, 12, 9, 7, 5, 3)

Device outputs. Depending upon the state of the outputenable pins, these outputs are either noninverting outputs or high-impedance outputs.

LOGIC DETAIL



OUTLINE DIMENSIONS



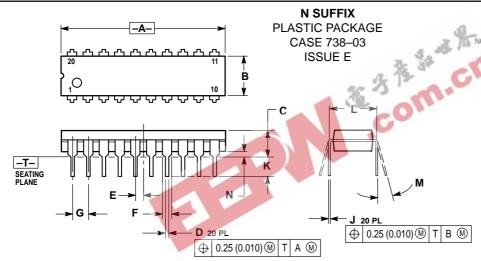
NOTES:

- UTES:

 1. LEADS WITHIN 0.25 (0.010) DIAMETER, TRUE
 POSITION AT SEATING PLANE, AT MAXIMUM
 MATERIAL CONDITION.

 2. DIMENSION L TO CENTER OF LEADS WHEN
 FORMED PARALLEL.
- 3. DIMENSIONS A AND B INCLUDE MENISCUS.

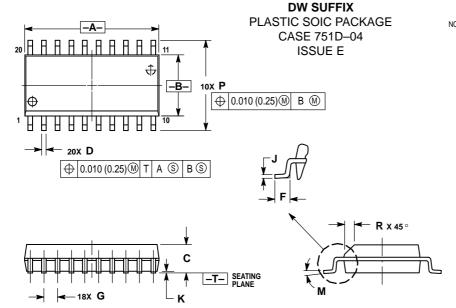
	MILLIMETERS INC			HES
DIM	MIN	MAX	MIN	MAX
Α	23.88	25.15	0.940	0.990
В	6.60	7.49	0.260	0.295
С	3.81	5.08	0.150	0.200
D	0.38	0.56	0.015	0.022
F	1.40	1.65	0.055	0.065
G	2.54	BSC	0.100 BSC	
Н	0.51	1.27	0.020	0.050
J	0.20	0.30	0.008	0.012
K	3.18	4.06	0.125	0.160
٦	7.62 BSC		0.300 BSC	
М	0°	15°	0°	15°
И	0.25	1.02	0.010	0.040



- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

 2. CONTROLLING DIMENSION: INCH.
- DIMENSION L TO CENTER OF LEAD WHEN FORMED PARALLEL.
 DIMENSION B DOES NOT INCLUDE MOLD
- FLASH.

	INC	HES	MILLIN	IETERS
DIM	MIN MAX		MIN	MAX
Α	1.010	1.070	25.66	27.17
В	0.240	0.260	6.10	6.60
С	0.150	0.180	3.81	4.57
D	0.015	0.022	0.39	0.55
Е	0.050	BSC	1.27 BSC	
F	0.050	0.070	1.27	1.77
G	0.100	BSC	2.54	BSC
J	0.008	0.015	0.21	0.38
K	0.110	0.140	2.80	3.55
L	0.300	BSC	7.62 BSC	
M	0 °	15°	0° 15	
N	0.020	0.040	0.51	1.01



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NOTES

- IOTES:

 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

 2. CONTROLLING DIMENSION: MILLIMETER.

 3. DIMENSIONS A AND B DO NOT INCLUDE MOLD PROTRUSION.

 4. MAXIMUM MOLD PROTRUSION 0.150 (0.006) PER SIDE.

 5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.13 (0.005) TOTAL IN FECESS OF D DIMENSION (0.005) TOTAL IN EXCESS OF D DIMENSION AT MAXIMUM MATERIAL CONDITION.

	MILLIN	METERS	INC	HES
DIM	MIN	MAX	MIN	MAX
Α	12.65	12.95	0.499	0.510
В	7.40	7.60	0.292	0.299
С	2.35	2.65	0.093	0.104
D	0.35	0.49	0.014	0.019
F	0.50	0.90	0.020	0.035
G	1.27	BSC	0.050	BSC
J	0.25	0.32	0.010	0.012
K	0.10	0.25	0.004	0.009
М	0 °	7 °	0 °	7°
Р	10.05	10.55	0.395	0.415
R	0.25	0.75	0.010	0.029



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